

#### Features

- Epitaxial Planar Die Construction
- Low Collector-Emitter Saturation Voltage
- Ideal for Low Power Amplification and Switching
- Complementary NPN Type Available (2DD2652)
- Ultra-Small Surface Mount Package
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green Device" (Note 2)



2DB1689

LOW V<sub>CE(SAT)</sub> PNP SURFACE MOUNT TRANSISTOR

#### **Mechanical Data**

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Alloy42 leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)



Top View



**Device Schematic** 

## **Maximum Ratings** $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-15	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-12	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Collector Current - Continuous	Ic	-1.5	А
Peak Pulse Collector Current	I <sub>CM</sub>	-3	А

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ $T_A = 25^{\circ}C$	PD	300	mW
Thermal Resistance, Junction to Ambient (Note 3) @ T <sub>A</sub> = 25°C	$R_{ ext{ heta}JA}$	417	°C/W
Power Dissipation (Note 4) @ $T_A = 25^{\circ}C$	PD	500	mW
Thermal Resistance, Junction to Ambient (Note 4) @ T <sub>A</sub> = 25°C	$R_{ ext{ heta}JA}$	250	°C/W
Operating and Storage Temperature Range	TJ, T <sub>STG</sub>	-55 to +150	°C

#### **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-15			V	$I_{C} = -10 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage (Note 5)	V <sub>(BR)CEO</sub>	-12	_		V	$I_{\rm C} = -1 {\rm mA}, \ I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	-6	_	_	V	$I_{E} = -10\mu A$ , $I_{C} = 0$
Collector Cut-Off Current	I <sub>СВО</sub>	_	_	-0.1	μΑ	$V_{CB} = -15V, I_E = 0$
Emitter Cut-Off Current	I <sub>EBO</sub>	_	_	-0.1	μΑ	$V_{EB} = -6V, I_{C} = 0$
ON CHARACTERISTICS (Note 5)						
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	-110	-200	mV	$I_{C} = -500 \text{mA}, I_{B} = -25 \text{mA}$
DC Current Gain		270	_	680		$V_{CE} = -2V, I_{C} = -200 \text{mA}$
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C <sub>obo</sub>		8.5	_	pF	$V_{CB} = -10V, I_E = 0,$ f = 1MHz
Current Gain-Bandwidth Product	f⊤		300	_	MHz	$V_{CE} = -2V, I_C = -100mA, f = 100MHz$

1. No purposefully added lead.

2. Diode's Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

3. Device mounted on FR-4 PCB with minimum recommended pad layout.

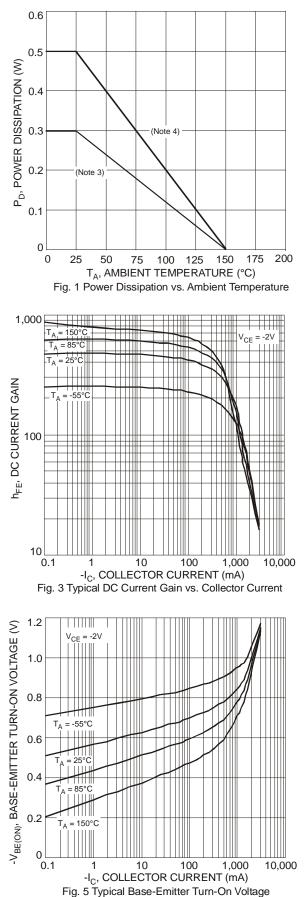
4. Device mounted on FR-4 PCB with 1 inch<sup>2</sup> copper pad layout.

5. Measured under pulsed conditions. Pulse width =  $300\mu s$ . Duty cycle  $\leq 2\%$ .

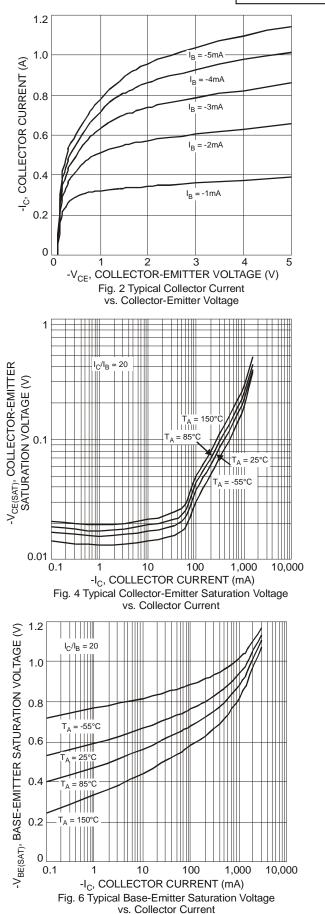
Notes:



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vs. Collector Current

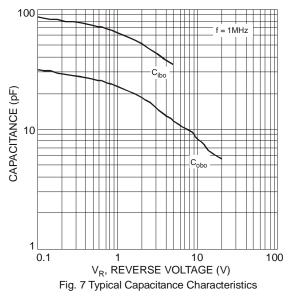


' 0.1 Fig.

NEW PRODUCT

2DB1689 Document number: DS31639 Rev. 2 - 2



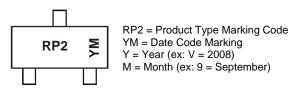


### Ordering Information (Note 6)

Part Number	Case	Packaging
2DB1689-7	SOT-323	3000/Tape & Reel

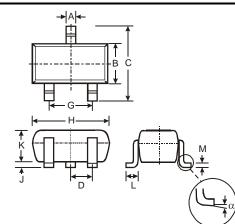
Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



Date Code Key												
Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	Х		Y	Z		А	В		С
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

## Package Outline Dimensions



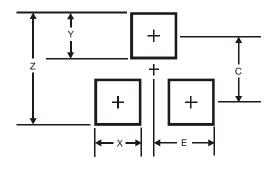
	SOT-323					
Dim	Min	Max	Тур			
Α	0.25	0.40	0.30			
В	1.15	1.35	1.30			
С	2.00	2.20	2.10			
D	-	-	0.65			
G	1.20	1.40	1.30			
Н	1.80	2.20	2.15			
J	0.0	0.10	0.05			
K	0.90	1.00	1.00			
L	0.25	0.40	0.30			
Μ	0.10	0.18	0.11			
α	0°	8°	-			
All	All Dimensions in mm					

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### Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0

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